ETEK Etek Microelectronics

1A Bipolar Linear Regulator

General Description

The ET1117 series are the low dropout three-terminal regulators with fixed output and ADJ output.

The ET1117 series features dropout of 1.3V at 1A load current and very low standby current 2mA.

ET1117 series offers thermal shut down function to assure the stability of chip and power system.

The ET1117 series are available in the SOT-223 package.

Features

- Maximum Output Current is 1.2A (TYP)
- Range of Operation Input Voltage up to 15V (MAX)
- Line Regulation is 0.03%/V (TYP)
- Standby Current is 2mA (TYP)
- Low Dropout Voltage is 1.3V(TYP)@1A
- Environment Temperature Range is -40°C~85°C
- Package is SOT-223 for Good Heat Dissipation

Applications

- Power Management for Computer Mother
- Board, Graphic Card
- LCD Monitor and LCD TV
- ADSL Modem
- Post Regulators For Switching Supplies

Device Information

Part No.	VOUT Туре	Package
ET1117	ADJ Output	SOT-223
ET1117V18	1.8V Fixed Output	SOT-223
ET1117V33	3.3V Fixed Output	SOT-223
ET1117V50	5.0V Fixed Output	SOT-223

Pin Configuration



Pin Function

Pin No.	Symbol	Pin Description
1		Ground Pin(Fixed Type)
1	1 VSS/ADJ	/ADJ Pin (ADJ Type)
2	VOUT	Output Pin
3	VIN	Input Pin

Block Diagram



Functional Description

ET1117 is a series of low dropout voltage, three terminal regulators. Its application circuit is very simple: the fixed version only needs two capacitors and the adjustable version only needs two resistors and two capacitors to work. It is composed of some modules including start-up circuit, bias circuit, band gap, thermal shutdown, power transistors and its driver circuit and so on.

The thermal shutdown modules can assure chip and its application system working safety when the junction temperature is larger than 125°C.

Thermal Considerations

We have to take heat dissipation into great consideration when output current or differential voltage of input and output voltage is large. Because in such cases, the power dissipation consumed by ET1117 is very large.

ET1117 series uses SOT-223 package type and its thermal resistance is about 20° C/W. And the copper area of application board can affect the total thermal resistance. If copper area is 5cm × 5cm (two sides), the resistance is about 30° C/W. So the total thermal resistance is about 20° C/W + 30° C/W. We can decrease total thermal resistance by increasing copper area in application board.

When there is no good heat dissipation copper are in PCB, the total thermal resistance will be as high as 120° C/W, then the power dissipation of ET1117 could allow on itself is less than 1W. And furthermore, ET1117 will work at junction temperature higher than 125° C under such condition and no lifetime is guaranteed.

Symbol	Parameter	Rating	Unit
V _{IN}	Input Voltage	-0.3~18	V
Іоит	Output Current	1.2	А
Тјмах	Operating Junction Temperature	150	°C
Tstg	Storage Temperature	-40~150	°C
PD	Power Dissipation (Standard Land Pattern)	1.25	W

Absolute Maximum Ratings

Note: Exceed these limits to damage to the device. Exposure to absolute maximum rating conditions may affect device reliability.

Recommended Work Conditions

Symbol	Parameter	Rating	Unit
VIN	Input Voltage	Max 15	V
Іоит	Output Current	Max 1.0	А
TJ	Operating Junction Temperature	-40 ~ 125	°C
T _A	Ambient Temperature	-40 ~ 85	°C

 $T_A=25^{\circ}C$, unless otherwise noted.

ET1117V18

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Vout	Output Voltage	0≤ I _{OUT} ≤1A , V _{IN} =3.8V	1.755	1.8	1.854	V
Vout	Output Voltage	3.8V≤ V _{IN} ≤12V , I _{OUT} =10mA	1.764	1.8	1.836	V
∆V _{OUT} /Vin	Line Regulation	I _{OUT} =10mA, 3.8V≤ V _{IN} ≤12V		0.03	0.2	%/V
∆Vouт/Iouт	Load Regulation	V _{IN} =3.3V, 10mA≤ I _{OUT} ≤1A		6	24	mV
	Dropout Voltage	I _{OUT} =100mA		1.15	1.3	V
V _{DIF}		І _{ОUT} =500mA		1.20	1.4	V
V DIF		I _{ОUT} =800mA		1.25	1.45	V
		Ι _{ΟUT} =1Α		1.3	1.5	V
la	Quiescent Current	V _{IN} =12V		2	5	mA
Ilimit	Max Limit Current	$V_{IN} - V_{OUT} = 5V$	1.2	1.4		А
PSRR	Ripple Rejection	V _{IN} – V _{OUT} = 3V, V _{RIPPLE} = 1V _{PP} , F= 120Hz		65		dB
ΔV/ΔΤ	Temperature Coefficient	-40 °C ~125 °C		±100		ppm

 $T_A=25^{\circ}C$, unless otherwise noted.

ET1117V33

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Vout	Output	0≤ I _{OUT} ≤1A , V _{IN} =5.3V	3.234	3.3	3.366	V
VOUI	Voltage	02 1001 21A, VIN-0.5V	5.254	5.5	5.500	v
Vout	Output	5.3V≤ V _{IN} ≤12V ,	3.234	3.3	3.366	V
001	Voltage	I _{OUT} =10mA	0.204	0.0	0.000	v
∆Vout/Vin	Line	Ι _{ΟUT} =10mA,		0.03	0.2	%/V
	Regulation	5.3V≤ V _{IN} ≤12V		0.00	0.2	707 V
∆Vouт/Iouт	Load	V _{IN} =4.8V,		6	24	mV
	Regulation	10mA≤ I _{OUT} ≤1A		0	24	
		I _{OUT} =100mA		1.15	1.3	V
V _{DIF}	Dropout	Ι _{ΟυΤ} =500mA		1.20	1.4	V
V DIF	Voltage	Ι _{ΟυΤ} =800mA		1.25	1.45	V
		Ι _{ΟυΤ} =1Α		1.3	1.5	V
lq	Quiescent	V _{IN} =12V		2	5	mA
	Current	VIN-IZV		2	5	
ILIMIT	Max Limit	VIN – VOUT = 5V	1.2	1.4		А
ILIMIT	Current		1.2	1.4		~
PSRR	Ripple	$V_{IN} - V_{OUT} = 3V$,		65		dB
FORIX	Rejection	V _{RIPPLE} = 1V _{PP} , F= 120Hz		05		uD
Δν/Δτ	Temperature	-40 ℃ ~125 ℃		±100		ppm
	Coefficient	-+0 0 123 0		100		Phili

 $T_A=25^{\circ}C$, unless otherwise noted.

ET1117V50

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Vout	Output	0≤ I _{OUT} ≤1A , V _{IN} =7.0V	4.90	5.0	5.10	V
VOUT	Voltage	02 1001 21A, VIN-7.0V	4.90	5.0	5.10	v
Vout	Output	7.0V≤ V _{IN} ≤12V ,	4.90	5.0	5.10	V
¥001	Voltage	I _{OUT} =10mA	4.30	5.0	5.10	v
∆Vout/Vin	Line	I _{ОUT} =10mА,		0.03	0.2	%/V
	Regulation	7.0V≤ V _{IN} ≤12V		0.00	0.2	707 V
∆Vouт/Iouт	Load	V _{IN} =6.5V,		6	24	mV
	Regulation	10mA≤ I _{OUT} ≤1A		0	24	IIIV
		I _{OUT} =100mA		1.15	1.3	V
M	Dropout	Iout =500mA		1.20	1.4	V
V _{DIF}	Voltage	I _{ОUT} =800mA		1.25	1.45	V
		Ι _{ΟυΤ} =1Α		1.3	1.5	V
lq	Quiescent	V _{IN} =12V		2	5	mA
īQ	Current	VIN-IZV		2	5	IIIA
ILIMIT	Max Limit	VIN – VOUT = 5V	1.2	1.4		А
ILIMIT	Current	VIN = VOUI = 3V	1.2 1.4			A
PSRR	Ripple	$V_{IN} - V_{OUT} = 3V$,		65		dB
FONIX	rejection	V _{RIPPLE} = 1V _{PP} , F= 120Hz		05		uD
Δν/Δτ	Temperature	- 40 ℃ ~125 ℃		±100		nnm
	Coefficient	- 40 0 120 0		100		ppm

 $T_A=25^{\circ}C$, unless otherwise noted.

ET1117

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
N/	Reference	V _{IN} -V _{OUT} =2V to 10V, 10mA≤I _{OUT} ≤1A 1.225		4.05	1.275	V
Vref	Voltage			1.25		
∆Vout/Vin	Line	Ι _{ουτ} =10mA,		0.03	0.2	%/V
	Regulation	V _{IN} -V _{OUT} =2V to 10V,		0.03	0.2	70/ V
∆Vout/Iout	Load	V_{IN} - V_{OUT} =1.5V ,		6	24	m)/
	Regulation	10mA≤ I _{OUT} ≤1A		0	24	mV
		I _{ОUT} =100mA		1.15	1.3	V
	Dropout	І _{ОUT} =500mA		1.20	1.4	V
Vdif	Voltage	I _{ОUT} =800mA		1.25	1.45	V
		Ι _{ΟυΤ} =1Α		1.3	1.5	V
	Min Load	V _{IN} =12V		2	5	
I _{MIN}	Current (1)	VIN-IZV		2		mA
ILIMIT	Max Limit	V _{IN} – Vout = 5V	1.2	1.4		А
ILIMII	Current	VIN = VOUI = 5V	1.2	1.4		A
ladj	Adjust pin	V _{IN} =5V,		55	120	uA
IADJ	current	10mA≤ I _{OUT} ≤1A		55	120	uA
Ichange	IADJ change	V _{IN} =5V,		0.2	10	uA
ICHANGE	TADJ CHANGE	10mA≤ I _{OUT} ≤1A	0.2		10	uA
PSRR	Ripple	$V_{IN} - V_{OUT} = 3V$,		65		dB
FUNN	rejection	V _{RIPPLE} = 1V _{PP} , F= 120Hz		00		UD
Δν/Δτ	Temperature	-40 ℃ ~125 ℃		±100		nnm
	Coefficient	-40 0 ~ 125 0	±100			ppm

Note1: Load current smaller than minimum load current of ET1117 will lead to unstable or oscillation output.

Application Circuits



*Note**: For ET1117 (ADJ Type): $V_{OUT} = V_{REF} (1+R2/R1) + I_{ADJ} \times R2$

Package Dimension

SOT-223



Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking	
1.0	2017-12-26	Original version	Shibo	Shibo	Zhujl	
1.1	2019-01-25	Revise package size	Wuy	Wuy	Liujy	
1.2	2022-11-11	Update Typeset	Shib	Shib	Liujy	
1.3	2022-12-07	Update Block	Wuhan	Shib	Liujy	
1.4 2023-5-9	2023-5-9	Load Regulation changed	Load Regulation changed	Shibo	Shibo	
1.4	2023-3-9	2023-5-9 Vin -Vout=1.5V		31100		

Revision History and Checking Table